# MIC94050/94051



### 4-Terminal SymFET™ P-Channel MOSFET

### **General Description**

The MIC94050 and MIC94051 are 4-terminal silicon gate P-channel MOSFETs that provide low on-resistance in a very small package.

Designed for high-side switch applications where space is critical, the MIC94050/1 exhibits an on-resistance of typically  $0.125\Omega$  at 4.5V gate-to-source voltage. The MIC94050/1 also operates with only 1.8V gate-to-source voltage.

The MIC94050 is the basic 4-lead P-channel MOSFET. The MIC94051 is a variation that includes an internal gate pullup resistor that can reduce the system parts count in many applications.

The 4-terminal SOT-143 package permits a substrate connection separate from the source connection. This 4-terminal configuration improves the  $\theta_{JA}$  (improved heat dissipation) and makes reverse-blocking switch applications practical.

The small size, low threshold, and low  $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$  make the MIC94050/1 the ideal choice for PCMCIA, USB, back-up battery-power, and distributed power management applications.



#### **Features**

- 0.125Ω typical on-resistance at 4.5V gate-to-source voltage
- Operates with 1.8V gate-to-source voltage
- Separate substrate connection allows reverse-blocking

#### Applications

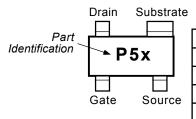
- Distributed power management
- PCMCIA card power management
- USB ports
- Battery-powered computers, peripherals
- Handheld bar-code scanners
- Portable communications equipment
- Reverse blocking battery management

#### Ordering Information

Part Number	Temp. Range*	Package	Pb-FREE
MIC94050BM4	–40°C to +150°C	SOT-143	NO
MIC94051BM4	–40°C to +150°C	SOT-143	NO
MIC94050YM4	–40°C to +150°C	SOT-143	YES
MIC94051YM4	–40° to +150°C	SOT-143	YES

Operating Junction Temperature

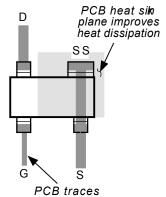
# **Pin Configuration**



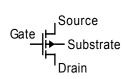
Part Number	Identification		
MIC94050BM4	P50		
MIC94051BM4	P51		
MIC94050YM4	<u>P</u> 50		
MIC94051YM4	<u>P</u> 51		

SOT-143 Package (M4)

### Typical PCB Layout

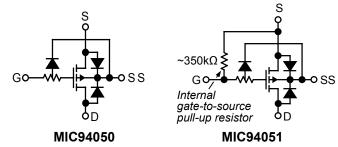


### Schematic Symbol



#### Schematic Symbol

### **Functional Diagrams**



SymFET is a trademark of Micrel, Inc.

# **Absolute Maximum Ratings**

Drain-to-Source Voltage
Gate-to-Source Voltage–6V
Continuous Drain Current
$T_A = 25^{\circ}C (V_{GS} = 4.5V) \dots 1.8A$
$T_A = 100^{\circ}C (V_{GS} = 4.5V) \dots 1.2A$
Total Power Dissipation
T <sub>A</sub> = 25°C568mW
$T_A = 100^{\circ}C$
Operating Junction Temperature40°C to +150°C
Storage Temperature–55°C to +150°C
ESD Rating, Note 2

# **Operating Ratings**

Thermal Resistance	
$\theta_{1\Delta}$	220°C/W
	130°C/W

# **Electrical Characteristics (Note 1)**

Symbol	Parameter	Condition (Note 1)	Min	Тур	Max	Units
$V_{GS}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	0.5		1.2	V
$I_{GSS}$	Gate-Body Leakage	$V_{DS} = 0V, V_{GS} = -4.5V, $ Note 2, Note 3			1	μA
$R_{GS}$	Gate-Source Resistance	$V_{DS} = 0V, V_{GS} = -4.5V, $ Note 2, Note 4	200	350	500	kΩ
$\overline{C_{ISS}}$	Input Capacitance	$V_{GS} = 0V, V_{DS} = -5.5V$		600		pF
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -5.5V, V_{GS} = 0V$			1	μA
		$V_{DS} = -5.5V, V_{GS} = 0V, T_{J} = 85^{\circ}C$			5	μA
R <sub>DS(ON)</sub>	Drain-Source On-Resistance	$V_{GS} = -4.5V, I_{D} = -100 \text{mA}$		0.125	0.160	Ω
_ (( )		$V_{GS} = -3.6V, I_{D} = -100mA$		0.135	0.180	Ω
		$V_{GS} = -2.5V$ , $I_D = -100$ mA		0.165	0.200	Ω
		$V_{GS} = -1.8V, I_{D} = -100mA$		0.225	0.320	Ω
$g_{FS}$	Forward Transconductance	$V_{DS} = -5.5V, I_{D} = -200mA, $ <b>Note 5</b>		3		S

Note 1.  $T_A = 25$ °C unless noted. Substrate connected to source for all conditions.

Note 2. ESD gate □

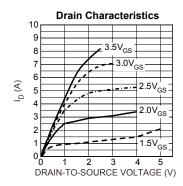
precautions required

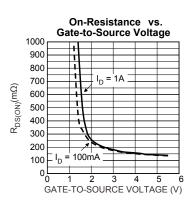
**Note 3.** MIC94050 only.

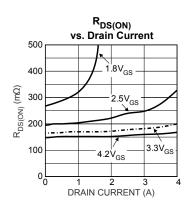
Note 4. MIC94051 only.

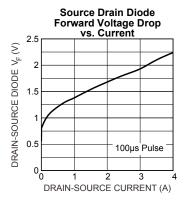
**Note 5.** Pulse Test: Pulse Width  $\leq 80\mu$ s, Duty Cycle  $\leq 0.5\%$ .

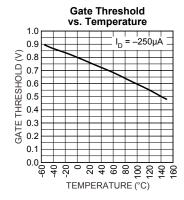
# **Typical Characteristics**

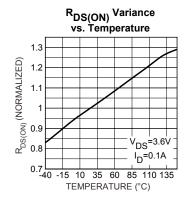












# **Typical Applications**

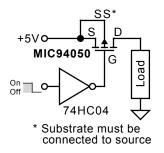


Figure 1. Load Switch Application

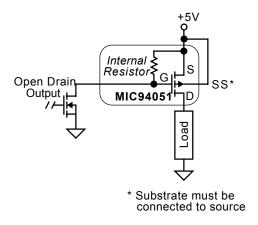


Figure 2. Load Switch Application (with internal gate-source pull-up)

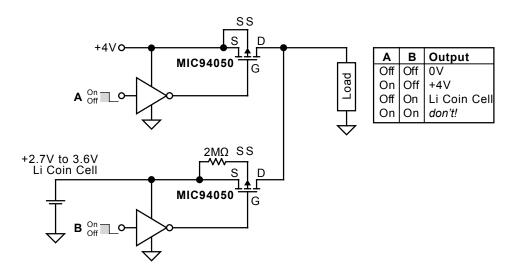
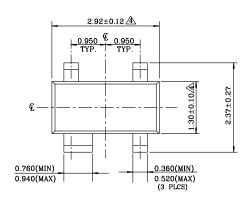
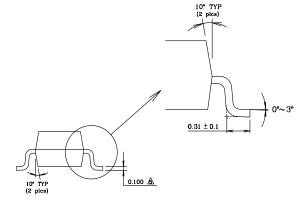


Figure 3. Reverse-Blocking Battery Back-Up Application

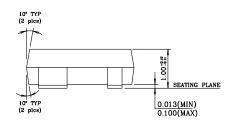
### **Package Information**



TOP VIEW



END VIEW



SIDE VIEW

#### NOTE:

- Dimensions and tolerances are as per ANSI Y14.5M, 1982.
- 2. Package surface to be mirror finish.
- 3. Die is facing up for mold & trim/form.
- <u>A</u> Dimension are exclusive of mold flash and gate burr.
- 5 Dimension are exclusive of solder plating.

SOT-143 (M4)

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